

74HC151D

1. Functional Description

- 8-Channel Multiplexer

2. General

The 74HC151D is a high speed CMOS 8-CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

One of eight data input signals (D0-D7) is selected by decoding of the three-bit address input (A, B, C). The selected data appears on two outputs: non-inverting (Y) and inverting (W).

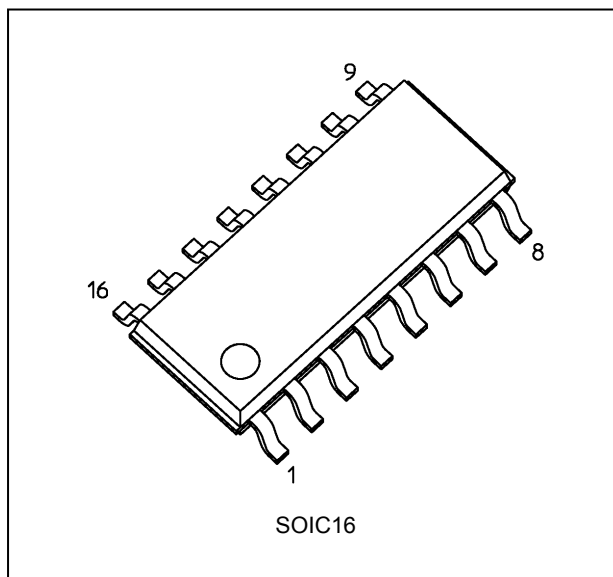
The strobe input provides two output conditions; a low level on the strobe input transfers the selected data to the outputs. A high level on the strobe input sets the Y output low and the W output high without regard to the data or select input conditions.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) High speed: $t_{pd} = 15 \text{ ns (typ.)}$ at $V_{CC} = 5 \text{ V}$
- (2) Low power dissipation: $I_{CC} = 4.0 \mu\text{A (max)}$ at $T_a = 25 \text{ }^\circ\text{C}$
- (3) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (4) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ to } 6.0 \text{ V}$

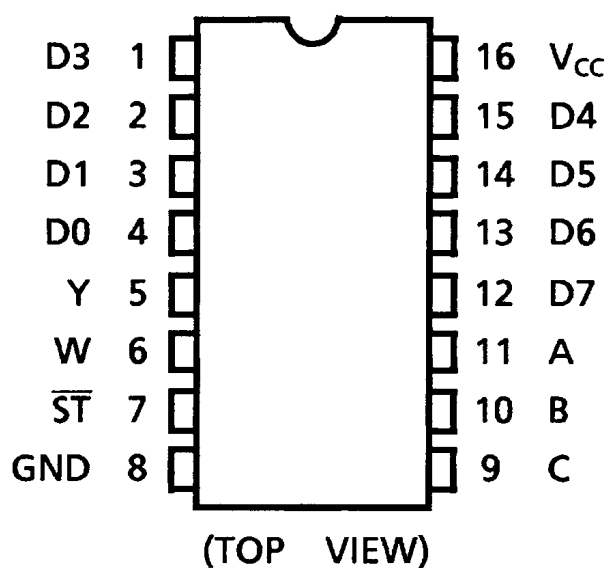
4. Packaging



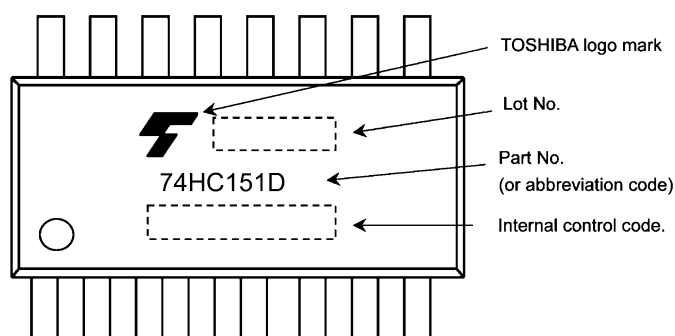
Start of commercial production

2016-05

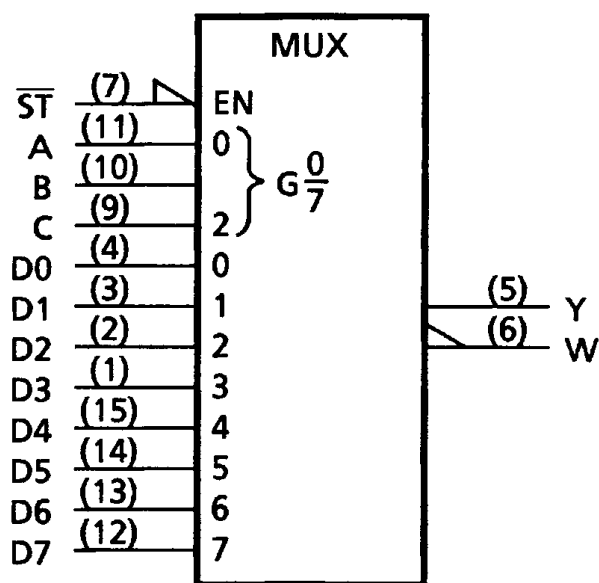
5. Pin Assignment



6. Marking



7. IEC Logic Symbol

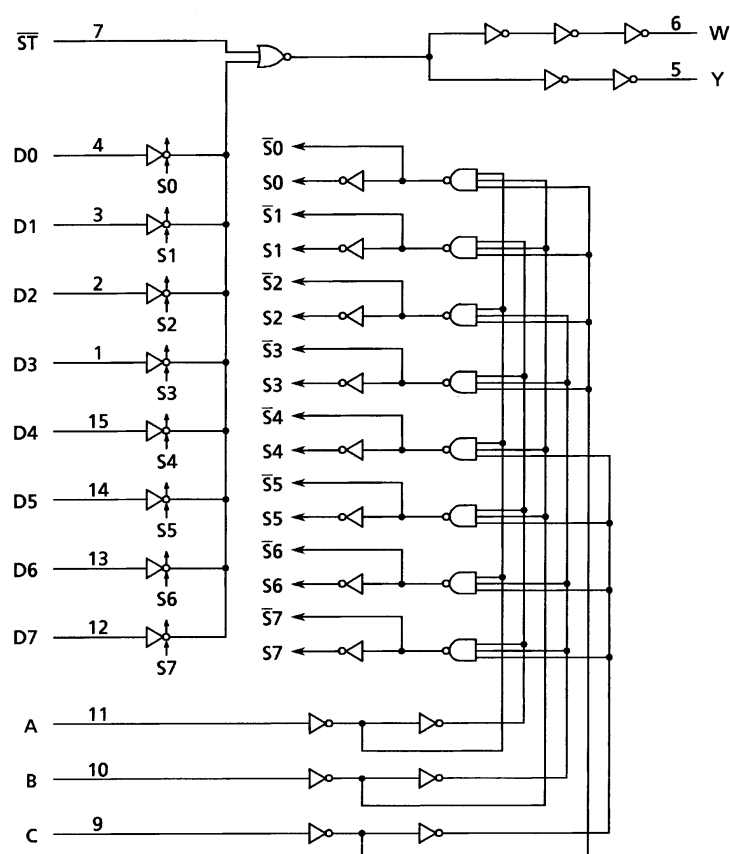


8. Truth Table

Inputs				Outputs	
Select			Strobe	Y	W
C	B	A	$\overline{ST}$		
X	X	X	H	L	H
L	L	L	L	D0	$\overline{D0}$
L	L	H	L	D1	$\overline{D1}$
L	H	L	L	D2	$\overline{D2}$
L	H	H	L	D3	$\overline{D3}$
H	L	L	L	D4	$\overline{D4}$
H	L	H	L	D5	$\overline{D5}$
H	H	L	L	D6	$\overline{D6}$
H	H	H	L	D7	$\overline{D7}$

X: Don't care

9. System Diagram



10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_{OUT}		-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}		± 20	mA
Output diode current	I_{OK}		± 20	mA
Output current	I_{OUT}		± 25	mA
V_{CC} /ground current	I_{CC}		± 50	mA
Power dissipation	P_D	(Note 1)	500	mW
Storage temperature	T_{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/°C above 85 °C

11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V_{CC}	—	2.0 to 6.0	V
Input voltage	V_{IN}	—	0 to V_{CC}	V
Output voltage	V_{OUT}	—	0 to V_{CC}	V
Operating temperature	T_{opr}	—	-40 to 125	°C
Input rise and fall times	t_r, t_f	—	0 to 50	μs

Note: The operating ranges must be maintained to ensure the normal operation of the device.

Unused inputs must be tied to either V_{CC} or GND.

12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	V
				4.5	3.15	—	—	
				6.0	4.20	—	—	
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	V
				4.5	—	—	1.35	
				6.0	—	—	1.80	
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\text{ }\mu\text{A}$	2.0	1.9	2.0	—	V
				4.5	4.4	4.5	—	
				6.0	5.9	6.0	—	
			$I_{OH} = -4\text{ mA}$	4.5	4.18	4.31	—	
			$I_{OH} = -5.2\text{ mA}$	6.0	5.68	5.80	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\text{ }\mu\text{A}$	2.0	—	0.0	0.1	V
				4.5	—	0.0	0.1	
				6.0	—	0.0	0.1	
			$I_{OL} = 4\text{ mA}$	4.5	—	0.17	0.26	
			$I_{OL} = 5.2\text{ mA}$	6.0	—	0.18	0.26	
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	± 0.1	μA
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	4.0	μA

12.2. DC Characteristics (Unless otherwise specified, $T_a = -40\text{ to }85\text{ }^{\circ}\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	V
				4.5	3.15	—	
				6.0	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	0.50	V
				4.5	—	1.35	
				6.0	—	1.80	
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\text{ }\mu\text{A}$	2.0	1.9	—	V
				4.5	4.4	—	
				6.0	5.9	—	
			$I_{OH} = -4\text{ mA}$	4.5	4.13	—	
			$I_{OH} = -5.2\text{ mA}$	6.0	5.63	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\text{ }\mu\text{A}$	2.0	—	0.1	V
				4.5	—	0.1	
				6.0	—	0.1	
			$I_{OL} = 4\text{ mA}$	4.5	—	0.33	
			$I_{OL} = 5.2\text{ mA}$	6.0	—	0.33	
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	± 1.0	μA
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	40.0	μA

12.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to $125\text{ }^\circ\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit
High-level input voltage	V_{IH}	—		2.0	1.50	—	V
				4.5	3.15	—	
				6.0	4.20	—	
Low-level input voltage	V_{IL}	—		2.0	—	0.50	V
				4.5	—	1.35	
				6.0	—	1.80	
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\text{ }\mu\text{A}$	2.0	1.9	—	V
				4.5	4.4	—	
				6.0	5.9	—	
			$I_{OH} = -4\text{ mA}$	4.5	3.7	—	
			$I_{OH} = -5.2\text{ mA}$	6.0	5.2	—	
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\text{ }\mu\text{A}$	2.0	—	0.1	V
				4.5	—	0.1	
				6.0	—	0.1	
			$I_{OL} = 4\text{ mA}$	4.5	—	0.4	
			$I_{OL} = 5.2\text{ mA}$	6.0	—	0.4	
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	± 1.0	μA
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	160.0	μA

12.4. AC Characteristics

(Unless otherwise specified, $C_L = 15\text{ pF}$, $V_{CC} = 5\text{ V}$, $T_a = 25\text{ }^\circ\text{C}$, Input: $t_r = t_f = 6\text{ ns}$)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH}, t_{THL}	—	—	4	8	ns
Propagation delay time (D-Y)	t_{PLH}, t_{PHL}	—	—	15	24	ns
Propagation delay time (D-W)	t_{PLH}, t_{PHL}	—	—	15	24	ns
Propagation delay time (ST-Y)	t_{PLH}, t_{PHL}	—	—	10	17	ns
Propagation delay time (ST-W)	t_{PLH}, t_{PHL}	—	—	10	17	ns
Propagation delay time (A, B, C-Y)	t_{PLH}, t_{PHL}	—	—	19	31	ns
Propagation delay time (A, B, C-W)	t_{PLH}, t_{PHL}	—	—	19	31	ns

12.5. AC Characteristics

(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = 25 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Note	V_{CC} (V)	Min	Typ.	Max	Unit
Output transition time	t_{TLH}, t_{THL}		2.0	—	30	75	ns
			4.5	—	8	15	
			6.0	—	7	13	
Propagation delay time (D-Y)	t_{PLH}, t_{PHL}		2.0	—	65	140	ns
			4.5	—	18	28	
			6.0	—	15	24	
Propagation delay time (D-W)	t_{PLH}, t_{PHL}		2.0	—	65	140	ns
			4.5	—	18	28	
			6.0	—	15	24	
Propagation delay time (ST-Y)	t_{PLH}, t_{PHL}		2.0	—	36	100	ns
			4.5	—	12	20	
			6.0	—	10	17	
Propagation delay time (ST-W)	t_{PLH}, t_{PHL}		2.0	—	36	100	ns
			4.5	—	12	20	
			6.0	—	10	17	
Propagation delay time (A, B, C-Y)	t_{PLH}, t_{PHL}		2.0	—	80	180	ns
			4.5	—	23	36	
			6.0	—	19	31	
Propagation delay time (A, B, C-W)	t_{PLH}, t_{PHL}		2.0	—	80	180	ns
			4.5	—	23	36	
			6.0	—	19	31	
Input capacitance	C_{IN}		—	—	3	—	pF
Power dissipation capacitance	C_{PD}	(Note 1)	—	—	15	—	pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}$$

12.6. AC Characteristics

(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = -40 \text{ to } 85 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

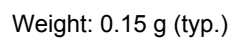
Characteristics	Symbol	$V_{CC} \text{ (V)}$	Min	Max	Unit
Output transition time	t_{TLH}, t_{THL}	2.0	—	95	ns
		4.5	—	19	
		6.0	—	16	
Propagation delay time (D-Y)	t_{PLH}, t_{PHL}	2.0	—	175	ns
		4.5	—	35	
		6.0	—	30	
Propagation delay time (D-W)	t_{PLH}, t_{PHL}	2.0	—	175	ns
		4.5	—	35	
		6.0	—	30	
Propagation delay time (ST-Y)	t_{PLH}, t_{PHL}	2.0	—	125	ns
		4.5	—	25	
		6.0	—	21	
Propagation delay time (ST-W)	t_{PLH}, t_{PHL}	2.0	—	125	ns
		4.5	—	25	
		6.0	—	21	
Propagation delay time (A, B, C-Y)	t_{PLH}, t_{PHL}	2.0	—	225	ns
		4.5	—	45	
		6.0	—	38	
Propagation delay time (A, B, C-W)	t_{PLH}, t_{PHL}	2.0	—	225	ns
		4.5	—	45	
		6.0	—	38	

12.7. AC Characteristics

(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = -40 \text{ to } 125 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	$V_{CC} \text{ (V)}$	Min	Max	Unit
Output transition time	t_{TLH}, t_{THL}	2.0	—	110	ns
		4.5	—	22	
		6.0	—	19	
Propagation delay time (D-Y)	t_{PLH}, t_{PHL}	2.0	—	210	ns
		4.5	—	42	
		6.0	—	36	
Propagation delay time (D-W)	t_{PLH}, t_{PHL}	2.0	—	210	ns
		4.5	—	42	
		6.0	—	36	
Propagation delay time (ST-Y)	t_{PLH}, t_{PHL}	2.0	—	150	ns
		4.5	—	30	
		6.0	—	26	
Propagation delay time (ST-W)	t_{PLH}, t_{PHL}	2.0	—	150	ns
		4.5	—	30	
		6.5	—	26	
Propagation delay time (A, B, C-Y)	t_{PLH}, t_{PHL}	2.0	—	270	ns
		4.5	—	54	
		6.5	—	46	
Propagation delay time (A, B, C-W)	t_{PLH}, t_{PHL}	2.0	—	270	ns
		4.5	—	54	
		6.0	—	46	

Unit: mm



Package Name(s)
Nickname: SOIC16

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